

INCHANGE SEMICONDUCTOR

isc P-Channel MOSFET Transistor

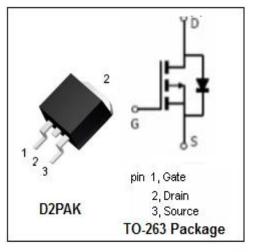
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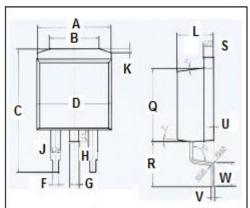
• FEATURES

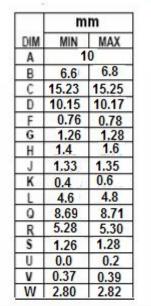
- P-channel
- With TO-263(D2PAK) packaging
- Uninterruptible power supply
- High speed switching
- Ultra low on-resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

APPLICATIONS

Switching applications







ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	-100	V	
V _{GSS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	-38 -24	А	
I _{DM}	Drain Current-Single Pulsed	-140	А	
P _D	Total Dissipation	170	W	
Tj	Operating Junction Temperature	-55~150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance 0.75		°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =- 0.25mA	-100			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =-0.25mA	-2		-4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = -10V; I _D =-38A			60	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = -100V; V _{GS} = 0V;Tj=25℃ V _{DS} = -80V; V _{GS} = 0V;Tj=125℃			25 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =-23A, V _{GS} = 0 V			-1.6	V

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